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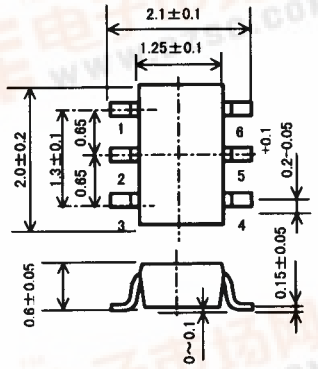
TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT6L61AT

VHF-UHF Band Low Noise Amplifier Application
VHF-UHF Band Oscillator Application

Unit: mm



1.COLLECTOR1 4.BASE2
2.EMITTER1 5.EMITTER2
3.COLLECTOR2 6.BASE1

JEDEC	—
JEITA	—
TOSHIBA	2-2JA1C

Weight: 0.008 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating		Unit
		Q1	Q2	
Collector-base voltage	V_{CBO}	10	10	V
Collector-emitter voltage	V_{CEO}	5	5	V
Emitter-base voltage	V_{EBO}	1.5	2	V
Collector current	I_C	25	40	mA
Base current	I_B	10	10	mA
Collector power dissipation	P_C (Note1)	200		mW
Junction temperature	T_j	125		°C
Storage temperature range	T_{stg}	−55~125		°C

Note1: Total power dissipation of Q1 and Q2

	Q1	Q2
Three pin SSM type part No.	MT3S07S	MT3S04AS

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Electrical Characteristics Q1-Side (Ta = 25°C)

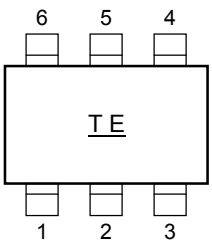
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 5 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 1 V, I_C = 0	—	—	1	μA
DC current gain	h_{FE}	V_{CE} = 1 V, I_C = 5 mA	70	—	140	—
Transition frequency	f_T	V_{CE} = 3 V, I_C = 10 mA	10	12	—	GHz
Insertion gain	$\|S_{21e}\|^2$ (1)	V_{CE} = 1 V, I_C = 5 mA, f = 2 GHz	—	6.5	—	dB
	$\|S_{21e}\|^2$ (2)	V_{CE} = 3 V, I_C = 15 mA, f = 2 GHz	4	7	—	
Noise figure	NF (1)	V_{CE} = 1 V, I_C = 5 mA, f = 2 GHz	—	1.6	3	dB
	NF (2)	V_{CE} = 3 V, I_C = 5 mA, f = 2 GHz	—	1.5	3	
Reverse transfer capacitance	C_{re}	V_{CB} = 1 V, I_E = 0, f = 1 MHz (Note2)	—	0.45	0.85	pF

Electrical Characteristics Q2-Side (Ta = 25°C)

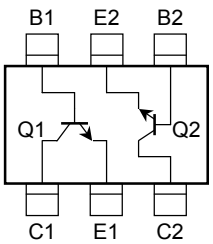
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 5 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 1 V, I_C = 0	—	—	1	μA
DC current gain	h_{FE}	V_{CE} = 1 V, I_C = 5 mA	80	—	160	—
Transition frequency	f_T (1)	V_{CE} = 1 V, I_C = 5 mA	2	4.5	—	GHz
	f_T (2)	V_{CE} = 3 V, I_C = 7 mA	5	7	—	
Insertion gain	$\|S_{21e}\|^2$ (1)	V_{CE} = 1 V, I_C = 5 mA, f = 1 GHz	—	8.5	—	dB
	$\|S_{21e}\|^2$ (2)	V_{CE} = 3 V, I_C = 20 mA, f = 1 GHz	7.5	11	—	
Noise figure	NF (1)	V_{CE} = 1 V, I_C = 5 mA, f = 1 GHz	—	1.3	2.2	dB
	NF (2)	V_{CE} = 3 V, I_C = 7 mA, f = 1 GHz	—	1.2	2	
Reverse transfer capacitance	C_{re}	V_{CB} = 1 V, I_E = 0, f = 1 MHz (Note2)	—	0.9	1.25	pF

Note2: C_{re} is measured by 3 terminal method with capacitance bridge.

Marking



Pin Assignment (top view)



Caution

This device electrostatic sensitivity. Please handle with caution.

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